

5 Ω , Quad, SPST, CMOS Analog Switches

ABSOLUTE MAXIMUM RATINGS

V+ to GND-0.3V to +44V
 V- to GND+0.3V to -44V
 V+ to V--0.3V to +44V
 VL to GND(GND - 0.3V) to (V+ + 0.3V)
 All Other Pins to DGND (Note 1) (V- - 0.3V) to (V+ + 0.3V)
 Continuous Current (COM_, NO_, NC_) ± 100 mA
 Peak Current (COM_, NO_, NC_) ± 300 mA
 (pulsed at 1ms, 10% duty cycle)

Continuous Power Dissipation (TA = +70°C)
 Narrow SO (derate 8.70mW/°C above +70°C)696mW
 Plastic DIP (derate 10.53mW/°C above +70°C)842mW
 Operating Temperature Ranges
 MAX466_C_E0°C to +70°C
 MAX466_E_E-40°C to +85°C
 Storage Temperature Range-65°C to +150°C
 Lead Temperature (soldering, 10sec)+300°C

Note 1: Signals on NC_, NO_, COM_, or IN_ exceeding V+ or V- are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = +15V, V- = -15V, VL = +5V, VIN_H = +2.4V, VIN_L = +0.8V, TA = TMIN to TMAX, unless otherwise noted. Typical values are at TA = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Input Voltage Range (Note 3)	V _{COM_} , V _{NO_} , V _{NC_}			V-		V+	V
COM_ to NO_ or NC_ On-Resistance	R _{ON}	I _{COM_} = 10mA, V _{NO_} or V _{NC_} = ±10V	T _A = +25°C	3	4	Ω	
			T _A = T _{MIN} to T _{MAX}	5			
COM_ to NO_ or NC_ On-Resistance Match Between Channels (Notes 3, 4)	ΔR _{ON}	I _{COM_} = 10mA, V _{NO_} or V _{NC_} = ±10V	T _A = +25°C	0.2	0.5	Ω	
			T _A = T _{MIN} to T _{MAX}	0.7			
COM_ to NO_ or NC_ On-Resistance Flatness (Notes 3, 5)	R _{FLAT(ON)}	I _{COM_} = 10mA; V _{NO_} or V _{NC_} = -5V, 0, 5V	T _A = +25°C	0.2	0.5	Ω	
			T _A = T _{MIN} to T _{MAX}	0.6			
Off-Leakage Current (NO_ or NC_) (Note 6)	I _{NO_} , I _{NC_}	V _{COM_} = ±10V, V _{NO_} or V _{NC_} = ∓10V	T _A = +25°C	-0.5	0.01	0.5	nA
			T _A = T _{MIN} to T _{MAX}	-5	5		
COM_ Off-Leakage Current (Note 6)	I _{COM_(OFF)}	V _{COM_} = ±10V, V _{NO_} or V _{NC_} = ∓10V	T _A = +25°C	-0.5	0.01	0.5	nA
			T _A = T _{MIN} to T _{MAX}	-5	5		
COM_ On-Leakage Current (Note 6)	I _{COM_(ON)}	V _{COM_} = ±10V, V _{NO_} or V _{NC_} = ±10V or floating	T _A = +25°C	-1	0.02	1	nA
			T _A = T _{MIN} to T _{MAX}	-10	10		
LOGIC INPUT							
Input Current with Input Voltage High	I _{IN_H}	IN_ = 2.4V, all others = 0.8V		-0.500	0.001	0.500	μA
Input Current with Input Voltage Low	I _{IN_L}	IN_ = 0.8V, all others = 2.4V		-0.500	0.001	0.500	μA
Logic Input Voltage High	V _{IN_H}			2.4			V
Logic Input Voltage Low	V _{IN_L}					0.8	V

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MAX4664/MAX4665/MAX4666

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

(V₊ = +15V, V₋ = -15V, V_L = +5V, V_{IN_H} = +2.4V, V_{IN_L} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
POWER SUPPLY							
Power-Supply Range				±4.5		±20.0	V
Positive Supply Current	I+	VIN = 0 or 5V	TA = +25°C	-0.5	0.001	0.5	μA
			TA = TMIN to TMAX	-5		5	
Negative Supply Current	I-	VIN = 0 or 5V	TA = +25°C	-0.5	0.001	0.5	μA
			TA = TMIN to TMAX	-5		5	
Logic Supply Current	IL	VIN = 0 or 5V	TA = +25°C	-0.5	0.001	0.5	μA
			TA = TMIN to TMAX	-5		5	
Ground Current	IGND	VIN = 0 or 5V	TA = +25°C	-0.5	0.001	0.5	μA
			TA = TMIN to TMAX	-5		5	
SWITCH DYNAMIC CHARACTERISTICS							
Turn-On Time	tON	Figure 2, VCOM_ = ±10V	TA = +25°C	130	275		ns
			TA = TMIN to TMAX		400		
Turn-Off Time	tOFF	Figure 2, VCOM_ = ±10V	TA = +25°C	90	175		ns
			TA = TMIN to TMAX		300		
Break-Before-Make Time Delay (MAX4666)		VCOM = 10V		5	30		ns
Charge Injection	Q	CL = 1.0nF, VGEN = 0, RGEN = 0, Figure 3			300		pC
Off-Isolation (Note 7)	VISO	RL = 50Ω, CL = 5pF, f = 1MHz, Figure 4			-62		dB
Crosstalk (Note 8)	VCT	RL = 50Ω, CL = 5pF, f = 1MHz, Figure 5			-60		dB
NC or NO Capacitance	COFF	f = 1MHz, Figure 6			34		pF
COM Off-Capacitance	CCOM	f = 1MHz, Figure 6			34		pF
On-Capacitance	CCOM	f = 1MHz, Figure 7			150		pF

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ELECTRICAL CHARACTERISTICS—Single Supply

(V₊ = +12V, V₋ = 0, V_L = +5V, V_{IN_H} = +2.4V, V_{IN_L} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Input Voltage Range (Note 3)	V _{COM_} , V _{NO_} , V _{NC_}			0		V+	V
COM_ to NO_ or NC_ On-Resistance	R _{ON}	I _{COM_} = 10mA, V _{NO_} or V _{NC_} = 10V	T _A = +25°C	5.5	8		Ω
			T _A = T _{MIN} to T _{MAX}	10			
COM_ to NO_ or NC_ On-Resistance Match Between Channels (Notes 3, 4)	ΔR _{ON}	I _{COM_} = 10mA, V _{NO_} or V _{NC_} = 10V	T _A = +25°C	0.05	0.5		Ω
			T _A = T _{MIN} to T _{MAX}	0.7			
COM_ to NO_ or NC_ On-Resistance Flatness (Notes 3, 5)	R _{FLAT(ON)}	I _{COM_} = 10mA; V _{NO_} or V _{NC_} = 3V, 6V, 9V	T _A = +25°C	0.25	1.1		Ω
			T _A = T _{MIN} to T _{MAX}	1.2			
Off-Leakage Current (NO_ or NC_) (Notes 6, 9)	I _{NO_} , I _{NC_}	V _{COM_} = 1V, 10V; V _{NO_} or V _{NC_} = 10V, 1V	T _A = +25°C	-0.5	0.01	0.5	nA
			T _A = T _{MIN} to T _{MAX}	-5	5		
COM_ Off-Leakage Current (Notes 6, 9)	I _{COM_(OFF)}	V _{COM_} = 1V, 10V; V _{NO_} or V _{NC_} = 10V	T _A = +25°C	-0.5	0.01	0.5	nA
			T _A = T _{MIN} to T _{MAX}	-5	5		
COM_ On-Leakage Current (Notes 6, 9)	I _{COM_(ON)}	V _{COM_} = 1V, 10V; V _{NO_} or V _{NC_} = 1V, 10V or floating	T _A = +25°C	-1	0.02	1	nA
			T _A = T _{MIN} to T _{MAX}	-10	10		
LOGIC INPUT							
Input Current with Input Voltage High	I _{IN_H}	I _{N_} = 2.4V, all others = 0.8V		-0.5	0.001	0.5	μA
Input Current with Input Voltage Low	I _{IN_L}	I _{N_} = 0.8V, all others = 2.4V		-0.5	0.001	0.5	μA
Logic Input Voltage High	V _{IN_H}			2.4			V
Logic Input Voltage Low	V _{IN_L}					0.8	V
POWER SUPPLY							
Power-Supply Range				4.5		36.0	V
Positive Supply Current	I ₊	V _{IN} = 0 or 5V	T _A = +25°C	-0.5	0.001	0.5	μA
			T _A = T _{MIN} to T _{MAX}	-5	5		
Logic Supply Current	I _L	V _{IN} = 0 or 5V	T _A = +25°C	-0.5	0.001	0.5	μA
			T _A = T _{MIN} to T _{MAX}	-5	5		
Ground Current	I _{GND}	V _{IN} = 0 or 5V	T _A = +25°C	-0.5	0.001	0.5	μA
			T _A = T _{MIN} to T _{MAX}	-5	5		

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MAX4664/MAX4665/MAX4666

ELECTRICAL CHARACTERISTICS—Single Supply (continued)

(V+ = +12V, V- = 0, V_L = +5V, V_{IN_H} = +2.4V, V_{IN_L} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
SWITCH DYNAMIC CHARACTERISTICS							
Turn-On Time (Note 3)	t _{ON}	Figure 2, V _{COM} _ = 10V	T _A = +25°C	225	400	ns	
			T _A = T _{MIN} to T _{MAX}	500			
Turn-Off Time (Note 3)	t _{OFF}	Figure 2, V _{COM} _ = 10V	T _A = +25°C	100	250	ns	
			T _A = T _{MIN} to T _{MAX}	350			
Break-Before-Make Time Delay (MAX4666)		V _{COM} = 10V		10	125	ns	
Charge Injection	Q	C _L = 1.0nF, V _{GEN} = 0, R _{GEN} = 0, Figure 3		25		pC	
Crosstalk (Note 8)	V _{CT}	R _L = 50Ω, C _L = 5pF, f = 1MHz, Figure 5		-60		dB	
NC_ or NO_ Capacitance	C _{OFF}	f = 1MHz, Figure 6		52		pF	
COM_Off-Capacitance	C _{COM}	f = 1MHz, Figure 6		52		pF	
On-Capacitance	C _{COM}	f = 1MHz, Figure 7		100		pF	

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

Note 3: Guaranteed by design.

Note 4: ΔRON = RON(MAX) - RON(MIN).

Note 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal range.

Note 6: Leakage parameters are 100% tested at maximum-rated hot temperature and guaranteed by correlation at +25°C.

Note 7: Off-isolation = 20log₁₀ [V_{COM} / (V_{NC} or V_{NO})], V_{COM} = output, V_{NC} or V_{NO} = input to off switch.

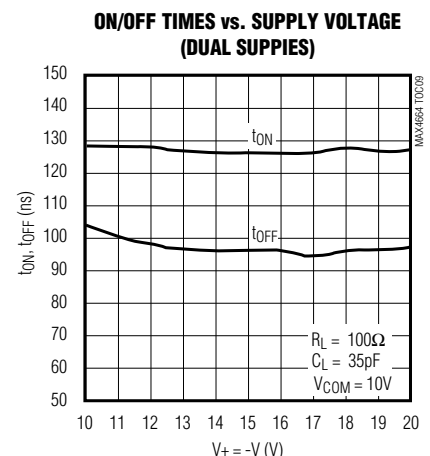
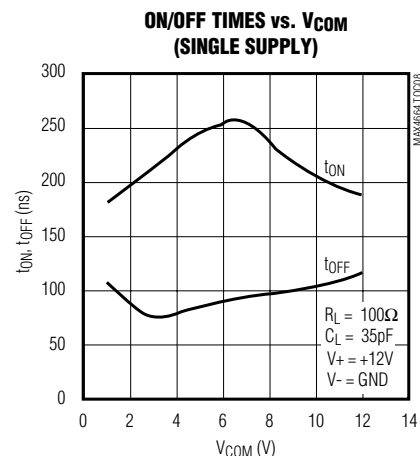
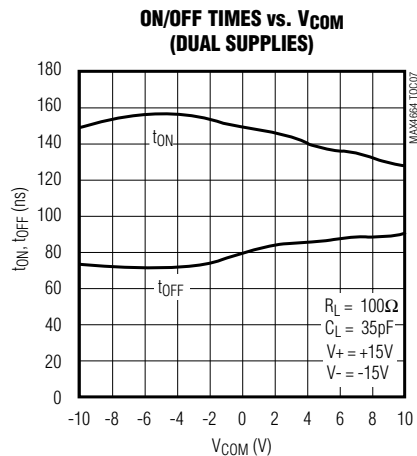
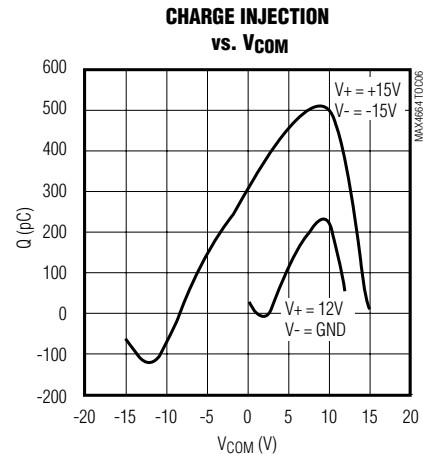
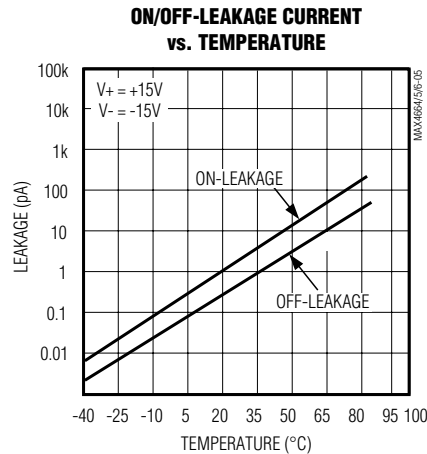
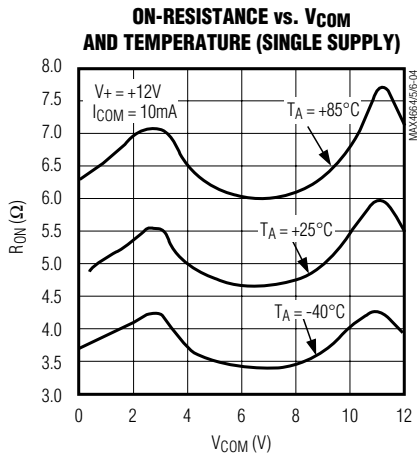
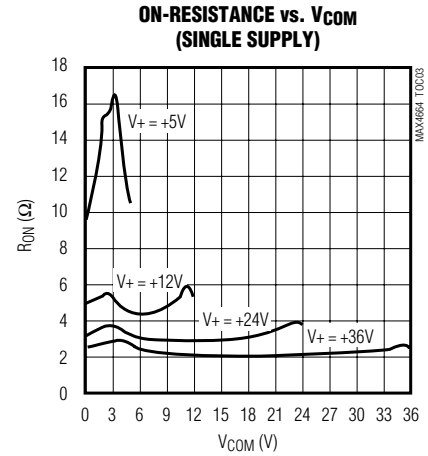
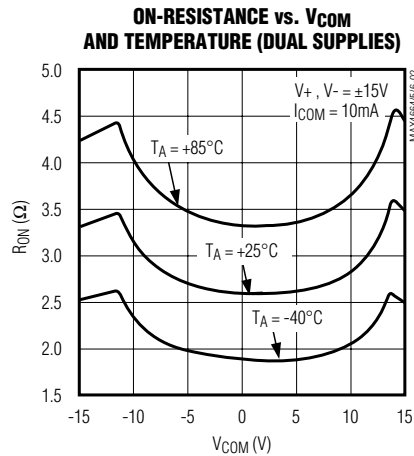
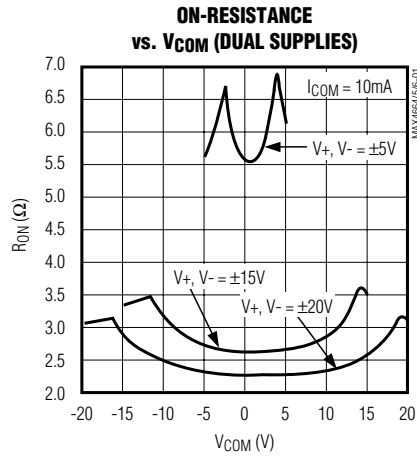
Note 8: Between any two switches.

Note 9: Leakage testing at single supply is guaranteed by testing with dual supplies.

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Typical Operating Characteristics

($T_A = +25^\circ\text{C}$, unless otherwise noted.)

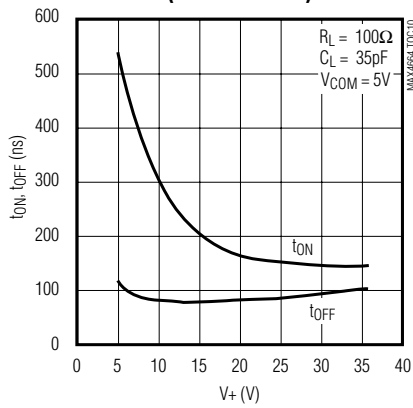


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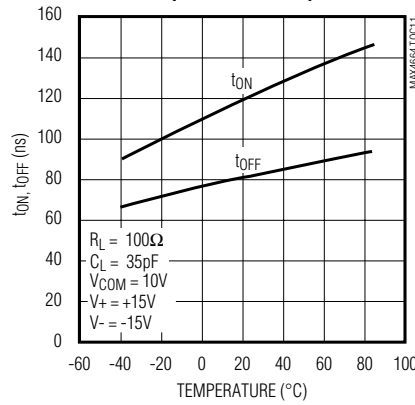
Typical Operating Characteristics (continued)

($T_A = +25^\circ\text{C}$, unless otherwise noted.)

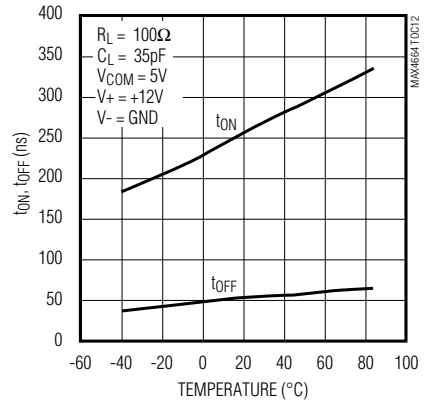
**ON/OFF TIMES vs. SUPPLY VOLTAGE
(SINGLE SUPPLY)**



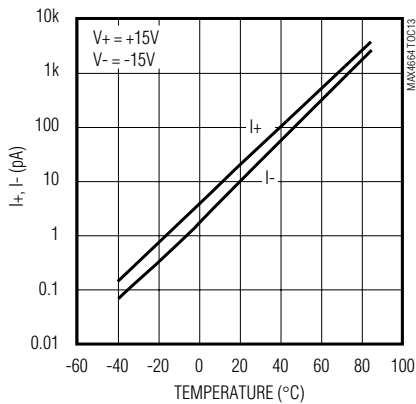
**ON/OFF TIMES vs. TEMPERATURE
(DUAL SUPPLIES)**



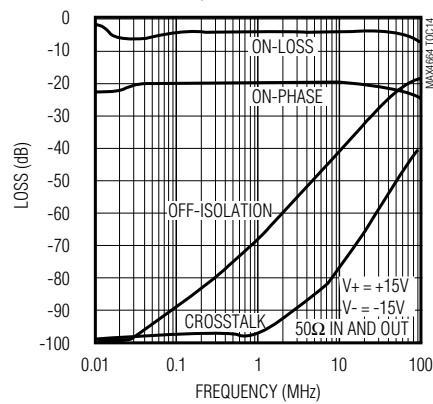
**ON/OFF TIMES vs. TEMPERATURE
(SINGLE SUPPLY)**



**SUPPLY CURRENT
vs. TEMPERATURE**



FREQUENCY RESPONSE



MAX4664/MAX4665/MAX4666

5Ω, Quad, SPST, CMOS Analog Switches

Pin Description

PIN			NAME	FUNCTION
MAX4664	MAX4665	MAX4666		
1, 16, 9, 8	1, 16, 9, 8	1, 16, 9, 8	IN1, IN2, IN3, IN4	Logic-Control Digital Inputs
2, 15, 10, 7	2, 15, 10, 7	2, 15, 10, 7	COM1, COM2, COM3, COM4	Analog Switch, Common Terminals
3, 14, 11, 6	–	–	NC1, NC2, NC3, NC4	Analog Switch, Normally Closed Terminals
–	3, 14, 11, 6	–	NO1, NO2, NO3, NO4	Analog Switch, Normally Open Terminals
–	–	3, 6	NO1, NO4	Analog Switch, Normally Open Terminal
–	–	14, 11	NC2, NC3	Analog Switch, Normally Closed Terminal
4	4	4	V-	Negative Analog Supply-Voltage Input. Connect to GND for single-supply operation.
5	5	5	GND	Ground
12	12	12	V _L	Logic-Supply Input
13	13	13	V+	Positive Analog Supply Input

Applications Information

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by the logic inputs, NO, or COM. If power-supply sequencing is not possible, add two small signal diodes (D1, D2) in series with supply pins (Figure 1). Adding diodes reduces the analog signal range to one diode drop below V+ and one diode drop above V-, but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V+ and V- should not exceed 44V. These protection diodes are not recommended when using a single supply.

Off-Isolation at High Frequencies

In 50Ω systems, the high-frequency on-response of these parts extends from DC to above 100MHz, with a typical loss of -2dB. When the switch is turned off, however, it behaves like a capacitor, and off-isolation decreases with increasing frequency. (Above 300MHz,

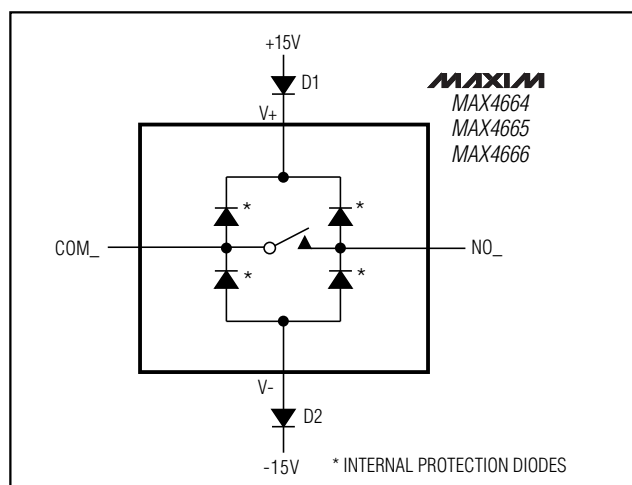


Figure 1. Overvoltage Protection Using External Blocking Diodes

the switch actually passes more signal turned off than turned on.) This effect is more pronounced with higher source and load impedances.

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Above 5MHz, circuit board layout becomes critical, and it becomes difficult to characterize the response of the switch independent of the circuit. The graphs shown in the *Typical Operating Characteristics* were taken using a 50Ω source and load connected with BNC connectors to a circuit board deemed "average,"

that is, designed with isolation in mind, but not using stripline or other special RF circuit techniques. For critical applications above 5MHz, use the MAX440, MAX441, and MAX442, which are fully characterized up to 160MHz.

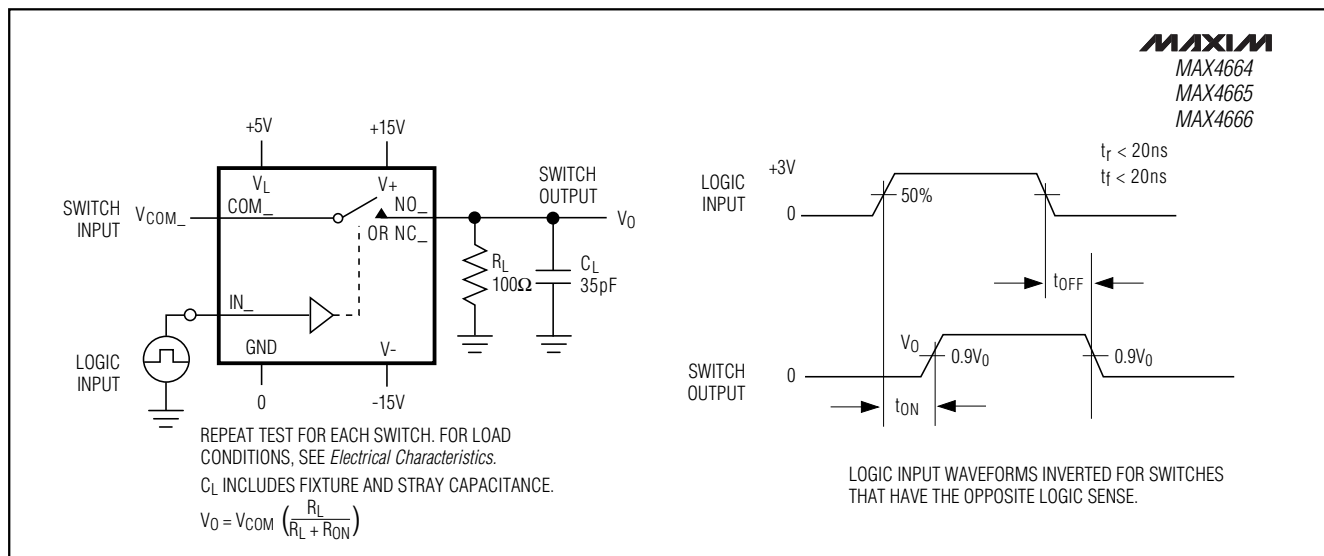


Figure 2. Switching-Time Test Circuit

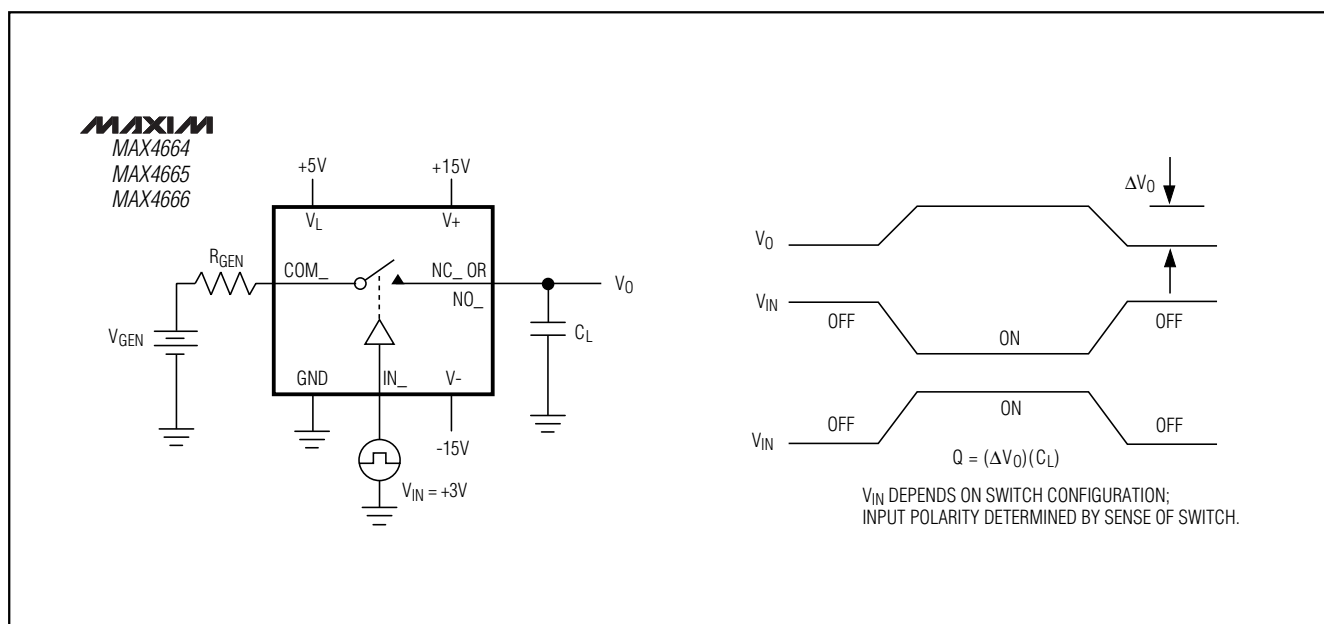


Figure 3. Charge-Injection Test Circuit

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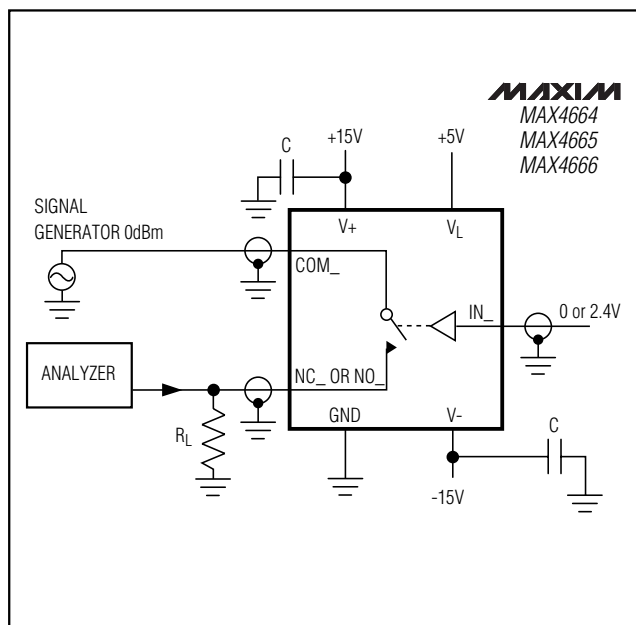


Figure 4. Off-Isolation Test Circuit

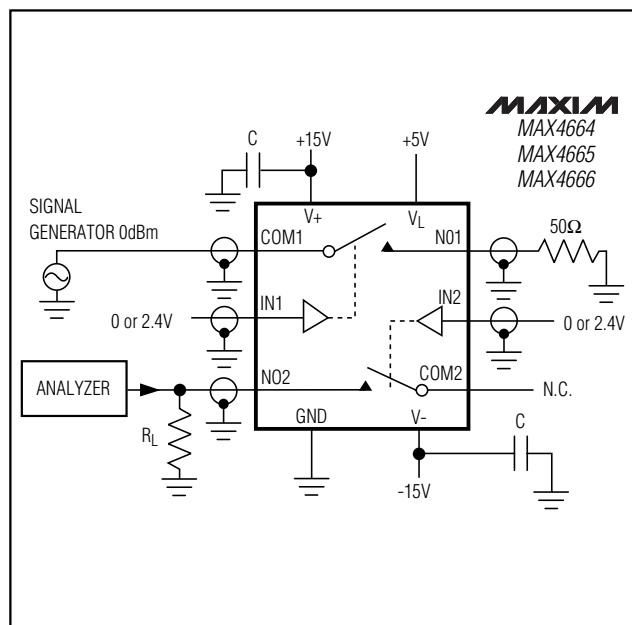


Figure 5. Crosstalk Test Circuit

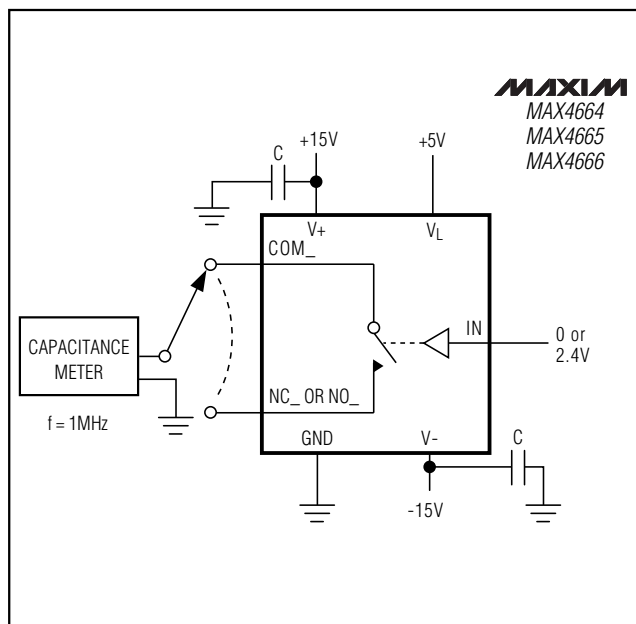


Figure 6. Switch Off-Capacitance Test Circuit

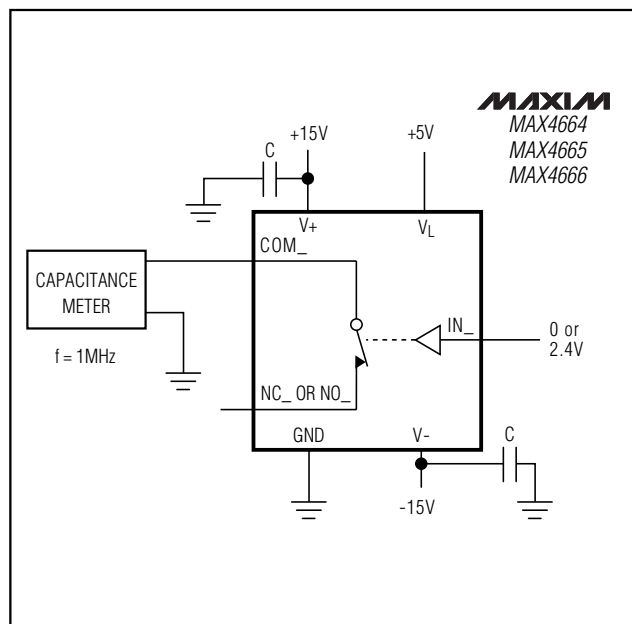


Figure 7. Switch On-Capacitance Test Circuit

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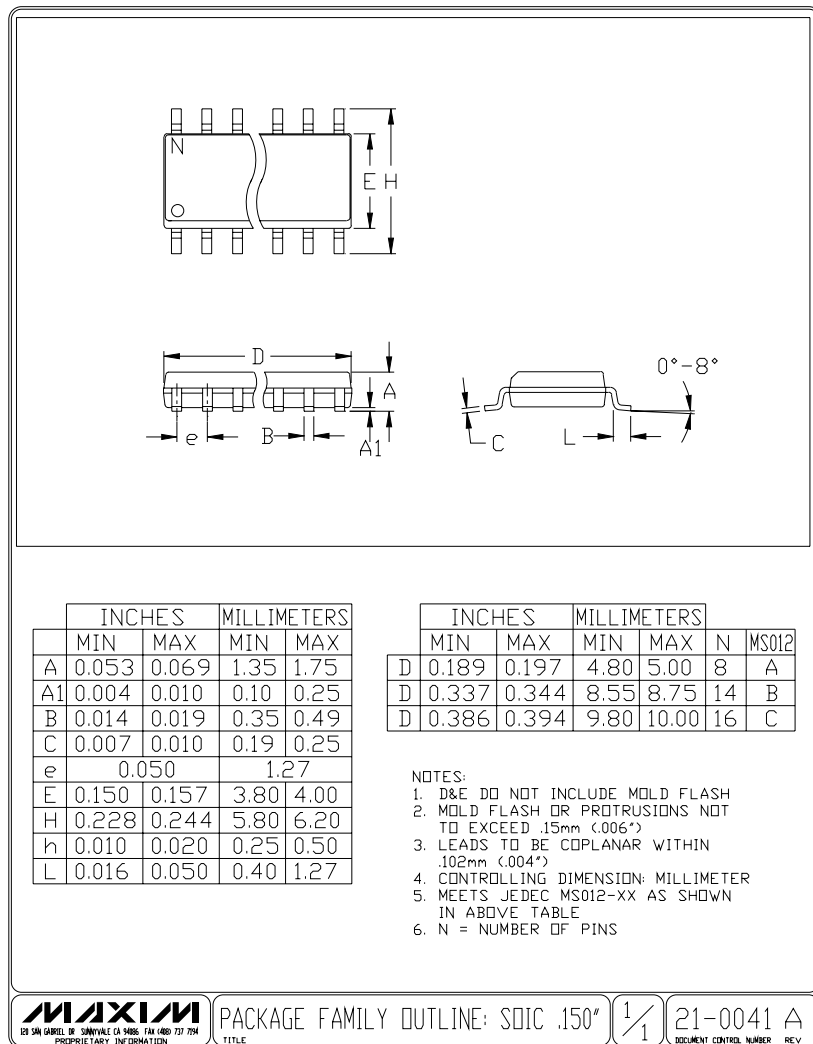
Ordering Information (continued)

PART	TEMP. RANGE	PIN-PACKAGE
MAX4665CSE	0°C to +70°C	16 Narrow SO
MAX4665CPE	0°C to +70°C	16 Plastic DIP
MAX4665ESE	-40°C to +85°C	16 Narrow SO
MAX4665EPE	-40°C to +85°C	16 Plastic DIP
MAX4666CSE	0°C to +70°C	16 Narrow SO
MAX4666CPE	0°C to +70°C	16 Plastic DIP
MAX4666ESE	-40°C to +85°C	16 Narrow SO
MAX4666EPE	-40°C to +85°C	16 Plastic DIP

Chip Information

TRANSISTOR COUNT: 108

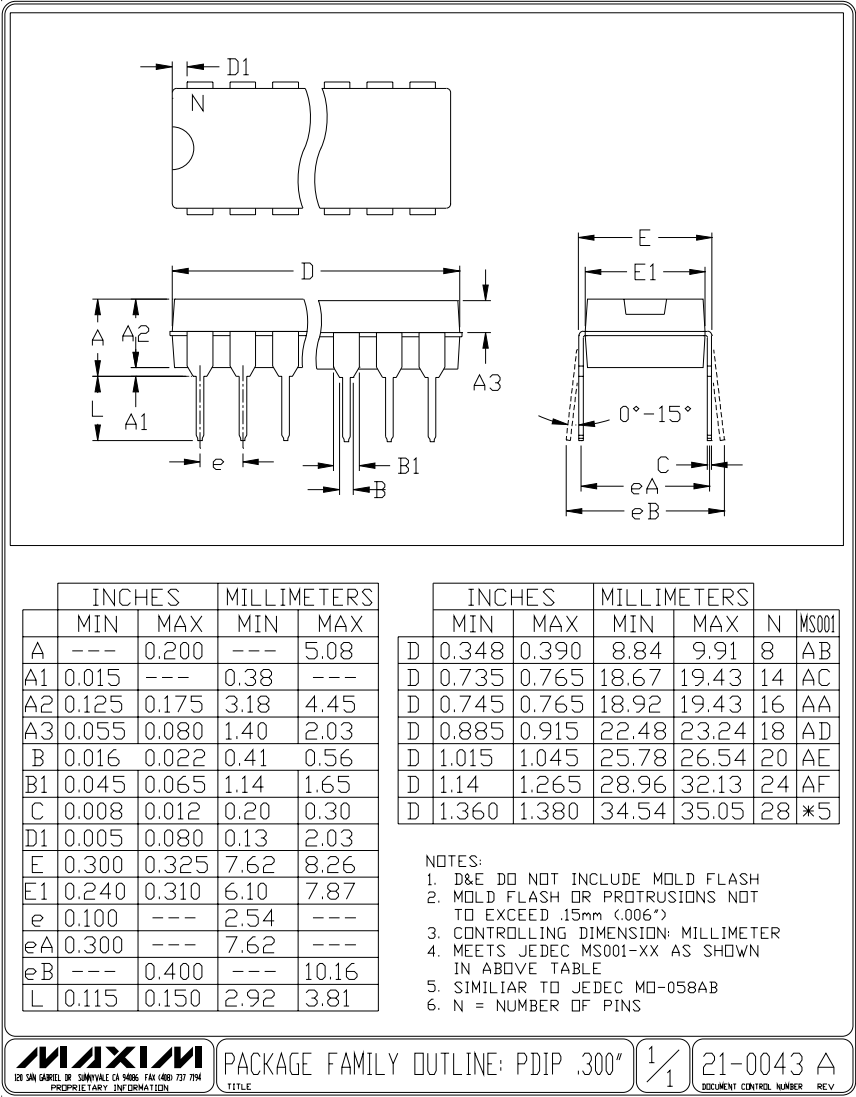
Package Information



MAX4664/MAX4665/MAX4666

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Package Information (continued)



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